

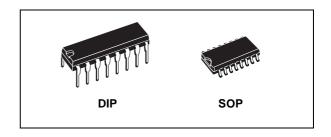
# **HCF4054B**

# 4 SEGMENT LIQUID CRYSTAL DISPLAY DRIVER WITH STROBED LATCH FUNCTION

- QUIESCENT CURRENT SPECIF. UP TO 20V
- OPERATION OF LIQUID CRYSTALS WITH CMOS CIRCUITS PROVIDES ULTRA LOW POWER DISPLAYS
- EQUIVALENT AC OUTPUT DRIVE FOR LIQUID CRYSTAL DISPLAYS - NO EXTERNAL CAPACITOR REQUIRED
- VOLTAGE DOUBLING ACROSS DISPLAY [(V<sub>DD</sub> - V<sub>EE</sub>) = 18V] RESULTS IN EFFECTIVE 36V (p-p) DRIVE ACROSS SELECTED DISPLAY SEGMENTS
- LOW OR HIGH OUTPUT LEVEL DC DRIVE FOR OTHER TYPES OF DISPLAYS
- ONE CHIP LOGIC LEVEL CONVERSION FOR DIFFERENT INPUT AND OUTPUT LEVEL SWINGS
- FULL DECODING OF ALL INPUT COMBINATIONS: "0 9, L, H, P, A" AND BLANK POSITIONS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

#### **DESCRIPTION**

HCF4054B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages.

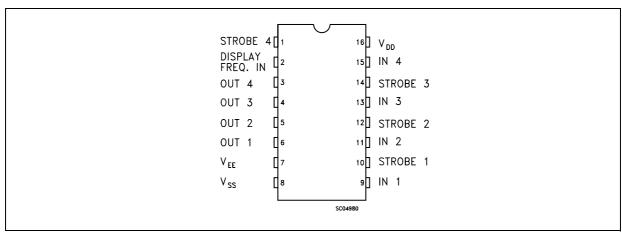


#### **ORDER CODES**

PACKAGE	TUBE	T&R
DIP	HCF4054BEY	
SOP	HCF4054BM1	HCF4054M013TR

HCF4054B provides level shifting similar to HCF4055B and HCF4056B, independently strobed latches, and common DF control on 4 signal lines. This device is intended to provide drive signal compatibility with HCF4055B and HCF4056B 7-segment decoder types for the decimal point, colon, polarity, and similar display lines. A level-shifted high amplitude DF output can be obtained from any HCF4054B output line by connecting the corresponding input and strobe lines to a low and high levels. HCF4054B may also be utilized for logic level "up conversion" or "down conversion" respectively. For example, input signal swings (VDD to VSS) from +5V to 0V

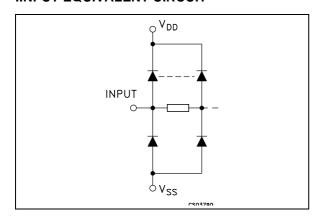
#### **PIN CONNECTION**



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can be converted to output signal swings ( $V_{DD}$  to  $V_{EE}$ ) of +5V to -5V. The level shifted function permits the use of different input and output signal swings. The input swings from a low level of  $V_{SS}$  to a high level of  $V_{DD}$ , while the outputs swings from a low level of  $V_{EE}$  to the same high level of  $V_{DD}$ . Thus, the input and output swings can be

#### **IINPUT EQUIVALENT CIRCUIT**



selected independently of each other over a 3 to 18V range.  $V_{SS}$  may be connected to  $V_{EE}$  when no level-shift function is required. Data is transferred from input to output by placing a high voltage level at the strobe input. A low voltage level at the strobe input latches the data input and the corresponding output segments remain selected (or non selected) while the strobe is low.

#### **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
6, 5, 4, 3	OUT1 to OUT4	Outputs
9, 11, 13, 15	IN1 to IN4	Inputs
10, 12, 14, 1	STROBE1 STROBE4	Strobe Input
2	DISPLAY FREQ. IN	Display Frequency Input
7	V <sub>EE</sub>	Negative Supply Voltage
8	$V_{SS}$	Negative Supply Voltage
16	$V_{DD}$	Positive Supply Voltage

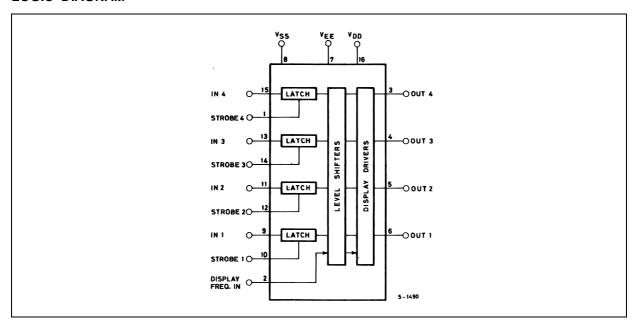
#### **TRUTH TABLE**

DF	IN	STROBE	OUT
L	L	Н	L
Н	L	Н	Н
L	Н	Н	Н
Н	Н	Н	L
Х	X	L	*

X = Don't Care.

(\*) Depends upon the input mode previously applied when ST=1.

## LOGIC DIAGRAM



## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
V <sub>I</sub>	DC Input Voltage	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC Input Current	± 10	mA
P <sub>D</sub>	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	3 to 20	V
V <sub>I</sub>	Input Voltage	0 to V <sub>DD</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

## **DC SPECIFICATIONS**

		Test Condition					Value							
Symbol	Parameter	V <sub>EE</sub>	Vı	٧o	V <sub>SS</sub>	V <sub>DD</sub>	T,	<sub>A</sub> = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		(V)	(V)	(V)	(V) (V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
IL	Quiescent Current	-5	0/5		0	5		0.04	5		150		150	
		0	0/10		0	10		0.04	10		300		300	μΑ
		0	0/15		0	15		0.04	20		600		600	μΛ
		0	0/20		0	20		0.08	100		3000		3000	
$V_{OH}$	High Level Output	0	0/5		0	5	4.95			4.95		4.95		
	Voltage	0	0/10		0	10	9.95			9.95		9.95		V
		0	0/15		0	15	14.95			14.95		14.95		
$V_{OL}$	Low Level Output	0	5/0		0	5		0.05			0.05		0.05	
	Voltage	0	10/0		0	10		0.05			0.05		0.05	V
		0	15/0		0	15		0.05			0.05		0.05	
$V_{IH}$	High Level Input	-5		0.5/4.5	0	5	3.5			3.5		3.5		
	Voltage	0		1/9	0	10	7			7		7		V
		0		1.5/18.5	0	15	11			11		11		
$V_{IL}$	Low Level Input	5		0.5/4.5	0	5			1.5		1.5		1.5	
	Voltage	0		9/1	0	10			3		3		3	V
		0		1.5/18.5	0	15			4		4		4	
I <sub>OH</sub>	Output Drive	-5	0/5	4.5	0	5	-0.38	-0.9		-0.28		-0.28		
	Current	0	0/10	9.5	0	10	-0.38	-0.9		-0.28		-0.28		mΑ
		0	0/15	13.5	0	15	-1.27	-3		-0.95		-0.95		
I <sub>OL</sub>	Output Sink	-5	0/5	0.4	0	5	1.1	2.6		0.82		0.82		
	Current	0	0/10	0.5	0	10	1.1	2.6		0.82		0.82		mΑ
		0	0/15	1.5	0	15	2.9	6.8		2.17		2.17		
lı	Input Leakage Current (any input)	0	0/18		0	18		±10 <sup>-5</sup>	±0.1		±1		±1	μΑ
C <sub>I</sub>	Input Capacitance (any input)							5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with  $V_{DD}$ =5V, 2V min. with  $V_{DD}$ =10V, 2.5V min. with  $V_{DD}$ =15V

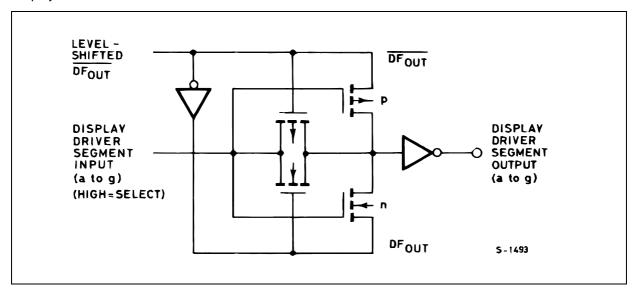
# **DYNAMIC ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25^{\circ}C$ , $C_{L} = 50 pF$ , $R_{L} = 200 K\Omega$ , $t_{f} = t_{f} = 20 ns$ )

Symbol Parar		Test Condition			ondition	Value (*)			Unit
	Parameter	V <sub>EE</sub> (V)	V <sub>SS</sub> (V)	V <sub>DD</sub> (V)		Min.	Тур.	Max.	
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay	-5	0	5			400	800	
	Time (any Input to	0	0	10			340	680	ns
	any Output)	0	0	15			250	500	
t <sub>THL</sub> t <sub>TLH</sub> Transition Time (any Output)	-5	0	5			100	200		
	(any Output)	0	0	10			100	200	ns
		0	0	15			75	150	
t <sub>setup</sub>	Data Setup Time	-5	0	5			220	110	
		0	0	10			100	50	ns
		0	0	15			70	35	
t <sub>W</sub>	Strobe Pulse Width	-5	0	5			220	110	
	0	0	10			100	50	ns	
		0	0	15			70	35	

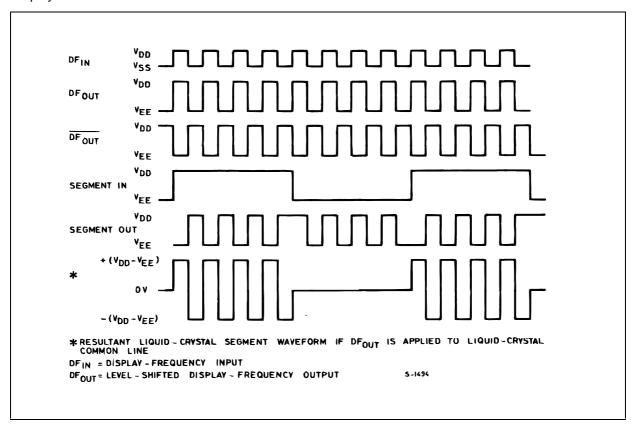
<sup>(\*)</sup> Typical temperature coefficient for all  $V_{DD}$  value is 0.3 %/°C.

# **TYPICAL APPLICATIONS**

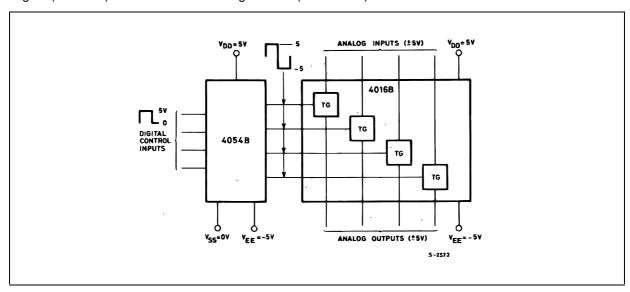
Display Driver Circuit.



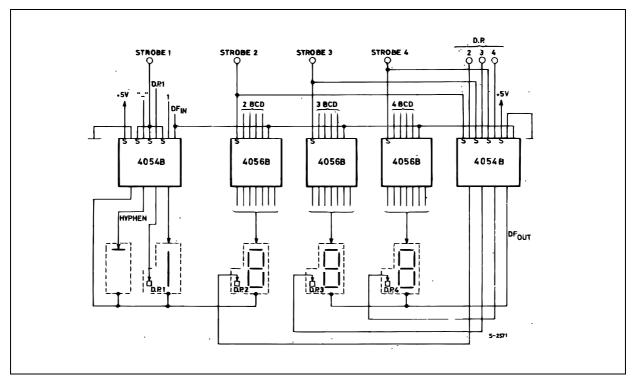
Display Driver Waveform..



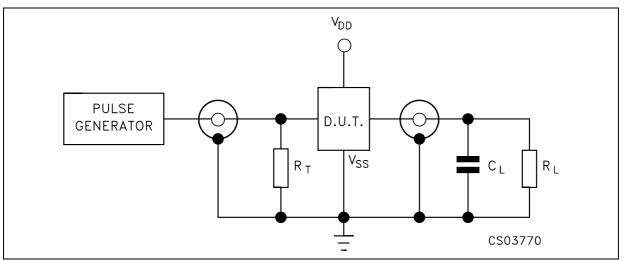
Digital (0 to +5V) to Bidirectional Analog Control (+5V to -5V) Level Shifter.



Typical 3½ Digit Crystal Display : ( $V_{DD}$  = +5V,  $V_{SS}$  = 0V,  $V_{EE}$  = -10V,  $DF_N$  = 30Hz Square)

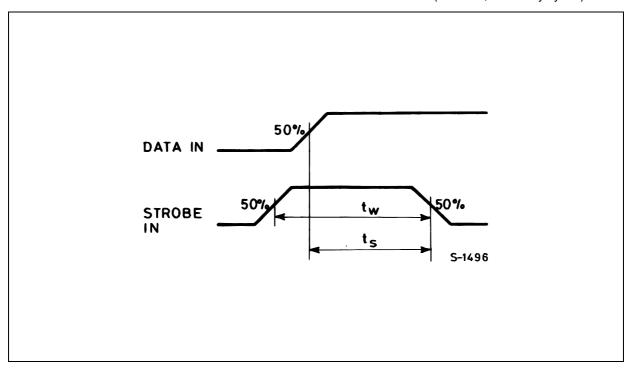


## **TEST CIRCUIT**



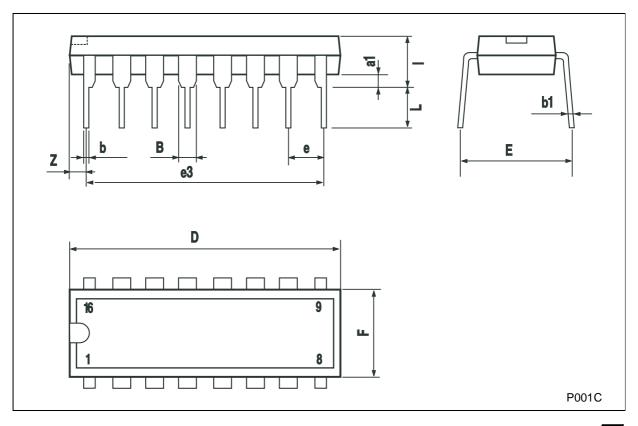
 $C_L$  = 50pF or equivalent (includes jig and probe capacitance)  $R_L$  = 200KΩ  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50Ω)

## WAVEFORM: DATA SETUP TIME AND STROBE PULSE DURATION (f=1MHz; 50% duty cycle)



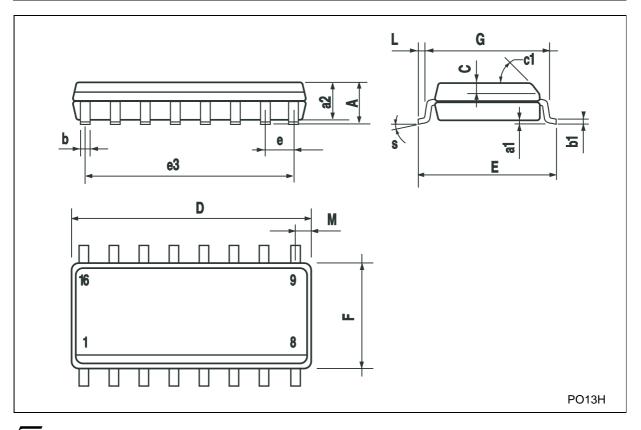
# Plastic DIP-16 (0.25) MECHANICAL DATA

DIM.		mm.		inch				
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
a1	0.51			0.020				
В	0.77		1.65	0.030		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
E		8.5			0.335			
е		2.54			0.100			
еЗ		17.78			0.700			
F			7.1			0.280		
I			5.1			0.201		
L		3.3			0.130			
Z			1.27			0.050		



# **SO-16 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)	•			
D	9.8		10	0.385		0.393		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		8.89			0.350			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.62			0.024		
S		•	8° (ı	max.)	•	1		



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